

Low Voltage, 1 Ω Single SPDT Analog Switch (1:2 Multiplexer) with Power Down Protection

DESCRIPTION

The DG4157 is a high performance single pole double throw analog switch designed for 1.65 V to 5.5 V operation with single power rail.

Fabricated with high density CMOS technology, the device achieves low on resistance as 1 Ω at 4.5 V power supply and fast switching speed. The - 3 dB bandwidth is typically 117 MHz.

The DG4157 features break before make switch performance, and guarantees logic high control input threshold as low as 1.4 V over the range up to 5.5 V.

It can handle both analog and digital signals and permits signals with amplitudes of up to V_{CC} to be transmitted in either direction.

Power down protection circuit is built in to prevent abnormal current path through signal pins during power down condition.

Each output pin (A, B₀, or B₁) can withstand greater than 8 kV (human body model).

It is available in both SC-70-6 and miniQFN6 packages.

The features make it an ideal part for the switching of audio, video, and data stream.

FEATURES

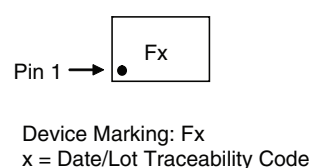
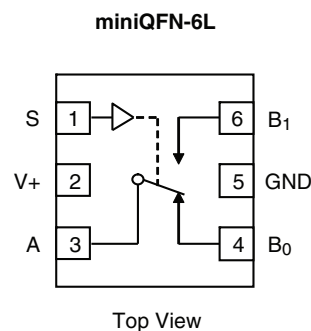
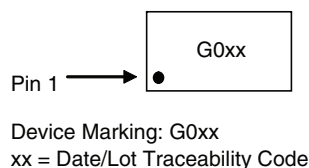
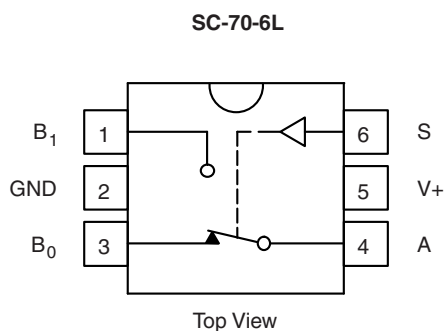
- Direct cross of industry standard xxx4157
- 1.65 V to 5.5 V operation voltage range
- Guaranteed 1.4 V logic high input threshold at $V_{CC} = 5.5$ V
- 117 MHz, - 3 dB bandwidth
- Low on-resistance
- Power down protection
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



Available

RoHS
COMPLIANT
HALOGEN
FREE

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE	
LOGIC INPUT (S)	FUNCTION
0	B ₀ Connected to A
1	B ₁ Connected to A

ORDERING INFORMATION		
TEMP. RANGE	PACKAGE	PART NUMBER
-40 °C to +85 °C	SC-70-6L	DG4157DL-T1-E3
	miniQFN-6L	DG4157DN-T1-E4

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER		LIMIT	UNIT
Reference V ₊ to GND		-0.3 to +6	V
S, A, B ^a		-0.3 to (V ₊ + 0.3)	
Continuous Current (Any terminal)		± 200	mA
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 400	
Storage Temperature	D Suffix	-65 to +150	°C
Power Dissipation (Packages) ^b	SC-70-6L ^c	250	mW
	miniQFN-6L ^d	160	

Notes

- a. Signals on A, or B or S exceeding V₊ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate 3.1 mW/°C above 70 °C.
d. Derate 2 mW/°C above 70 °C.

SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 3 V, VIN = 0 V or V+ ^e	TEMP. ^a	LIMITS -40 °C to +85 °C			UNIT
				MIN. ^b	TYP. ^c	MAX. ^b	
DC Characteristics							
On Resistance	RON	V+ = 2.7 V, B0 or B1 = 1.5 V, IO = 100 mA	Room	-	1.7	2.5	Ω
			Full	-	-	3	
		V+ = 4.5 V, B0 or B1 = 3.5 V, IO = 100 mA	Room	-	0.95	1.2	
			Full	-	-	1.4	
On Resistance Flatness	RFLATNESS	V+ = 2.7 V, B0 or B1 = 0.75 V, 1.5 V, IO = 100 mA	Room	-	0.2	-	
		V+ = 4.5 V, B0 or B1 = 1 V, 3.5 V, IO = 100 mA	Room	-	0.14	0.3	
			Full	-	-	0.4	
On Resistance Match	ΔRON	V+ = 2.7 V, B0 or B1 = 1.5 V, IO = 100 mA	Room	-	0.04	-	
			Room	-	0.05	0.12	
		V+ = 4.5 V, B0 or B1 = 3.5 V, IO = 100 mA	Full	-	-	0.15	
Switch Off Leakage Current	IOFF	V+ = 5.5 V, A = 1 V, 4.5 V B0 or B1 = 4.5 V, 1 V or floating	Room	-2	-	2	nA
Switch On Leakage Current	ION		Full	-20	-	20	
			Room	-4	-	4	
			Full	-40	-	40	
Digital Control							
Input, High Voltage	VINH	V+ = 2.7 V to 5.5 V	Full	1.4	-	-	V
Input, Low Voltage	VINL		Full	-	-	0.4	
Input Current	IINH, IINL	VIN = 0 or V+	Full	-1	-	1	μA
Power Supply							
Power Supply Range	V+		Full	1.65	-	5.5	V
Quiescent Supply Current	I+	V+ = 5.5 V, VIN = 0 V, 5.5 V	Room	-	0.05	0.5	μA
			Full	-	-	1	

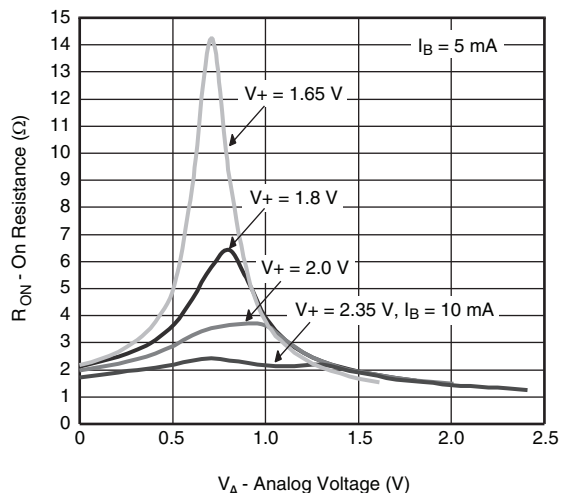
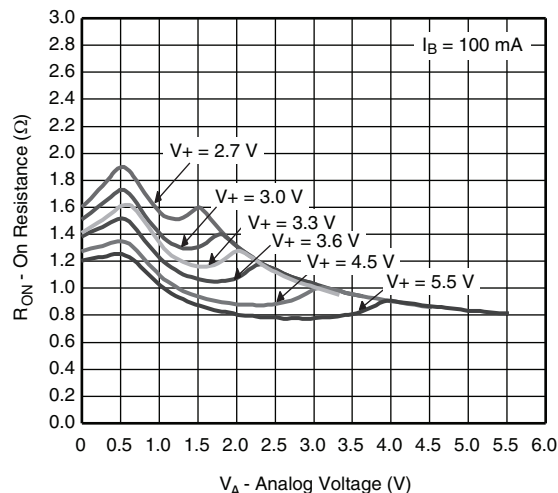
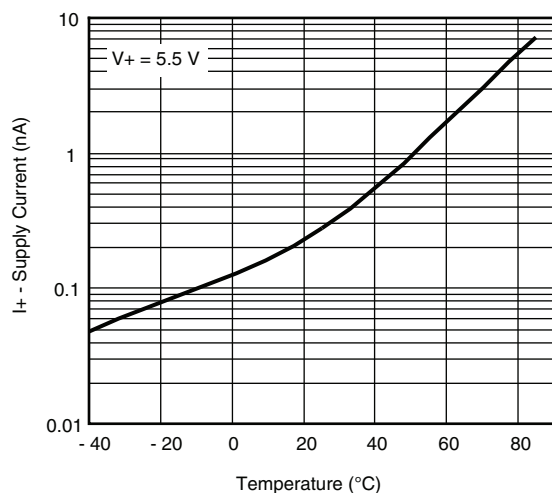
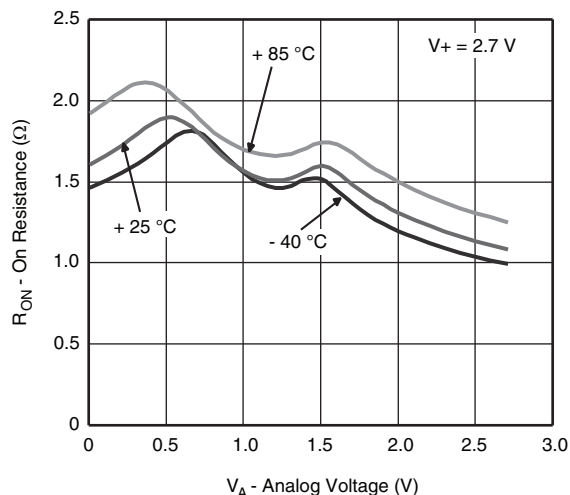
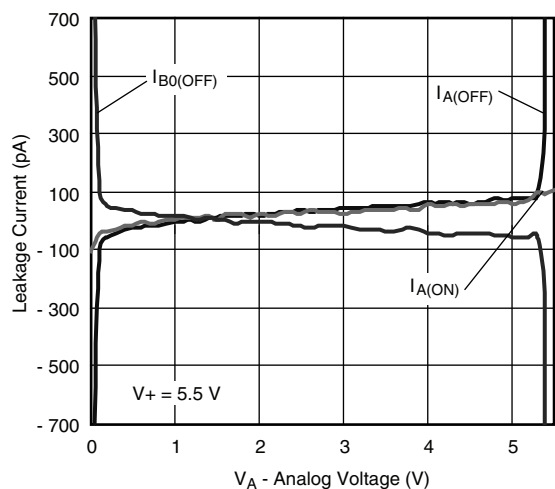
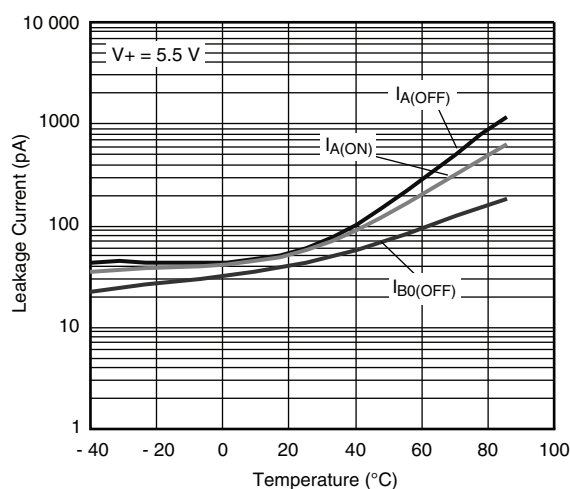


SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 3 V, VIN = 0 V or V+ ^e	TEMP. ^a	LIMITS -40 °C to +85 °C			UNIT
				MIN. ^b	TYP. ^c	MAX. ^b	
AC Characteristics							
Turn-On Time ^d	t _{ON}	V+ = 2.7 V, B ₀ or B ₁ = 1.5 V, R _L = 50 Ω, C _L = 35 pF	Room	-	40	55	ns
			Full	-	-	60	
		V+ = 4.5 V, B ₀ or B ₁ = 1.5 V, R _L = 50 Ω, C _L = 35 pF	Room	-	22	37	
			Full	-	-	40	
Turn-Off Time ^d	t _{OFF}	V+ = 2.7 V, B ₀ or B ₁ = 1.5 V, R _L = 50 Ω, C _L = 35 pF	Room	-	12	27	
			Full	-	-	30	
		V+ = 4.5 V, B ₀ or B ₁ = 1.5 V, R _L = 50 Ω, C _L = 35 pF	Room	-	8	23	
			Full	-	-	25	
Break-Before-Make Time ^d	t _{BBM}	V+ = 2.7 V, B ₀ = B ₁ = 1.5 V, R _L = 50 Ω, C _L = 35 pF	Room	1	26	-	
		V+ = 4.5 V, B ₀ = B ₁ = 1.5 V, R _L = 50 Ω, C _L = 35 pF		1	15	-	
Charge Injection ^d	Q	C _L = 1 nF, R _{GEN} = 0 Ω, V _{GEN} = 0 V	Room	-	50	-	pC
Off Isolation ^d	OIRR	R _L = 50 Ω, f = 1 MHz	Room	-	-58	-	dB
		R _L = 50 Ω, f = 10 MHz		-	-31	-	
Crosstalk ^d	X _{TALK}	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz	Room	-	-63	-	
		R _L = 50 Ω, C _L = 5 pF, f = 10 MHz		-	-36	-	
Bandwidth ^d	BW	R _L = 50 Ω	Room	-	117	-	MHz
Total Harmonic Distortion ^d	THD	R _L = 600 Ω, V _{IN} = 0.5 V, f = 20 kHz to 20 kHz	Room	-	0.02	-	%
Capacitance							
BX Port Off Capacitance ^d	C _{B(OFF)}	R _L = 50 Ω, C _L = 5 pF, f = 1 MHz	Room	-	20	-	pF
A Port On Capacitance ^d	C _{A(ON)}			-	57	-	
Control Pin Capacitance ^d	C _{IN}			-	5	-	

Notes

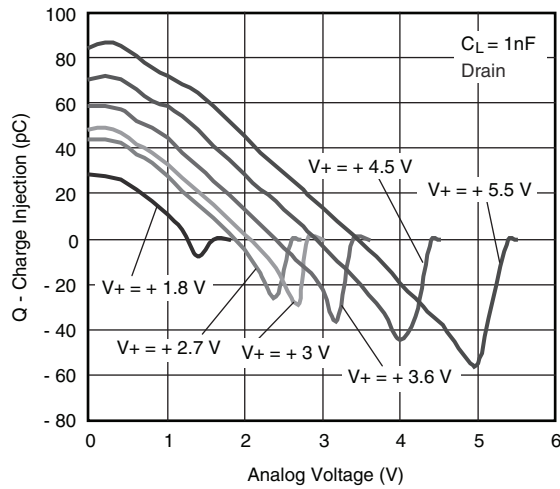
- a. Room = 25 °C, Full = as determined by the operating suffix.
b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
c. Typical values are for design aid only, not guaranteed nor subject to production testing.
d. Guarantee by design, nor subjected to production test.
e. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

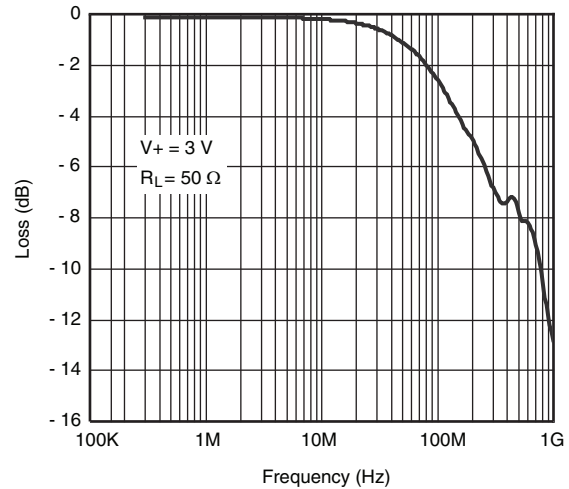
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)

 R_{ON} vs. V_A and Supply Voltage

 R_{ON} vs. V_A and Supply Voltage

Supply Current vs. Temperature

 R_{ON} vs. V_D and Temperature

Leakage vs. Analog Voltage

Leakage Current vs. Temperature



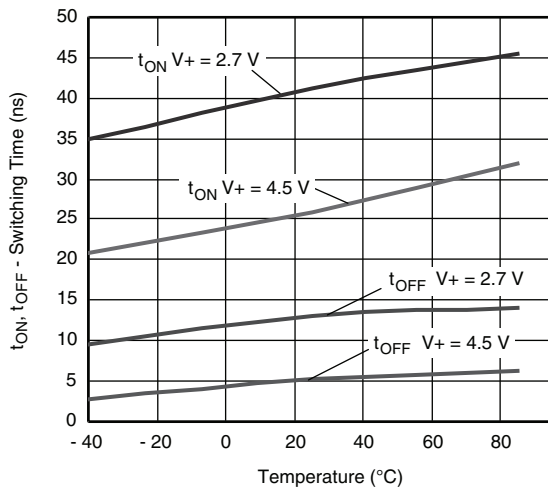
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



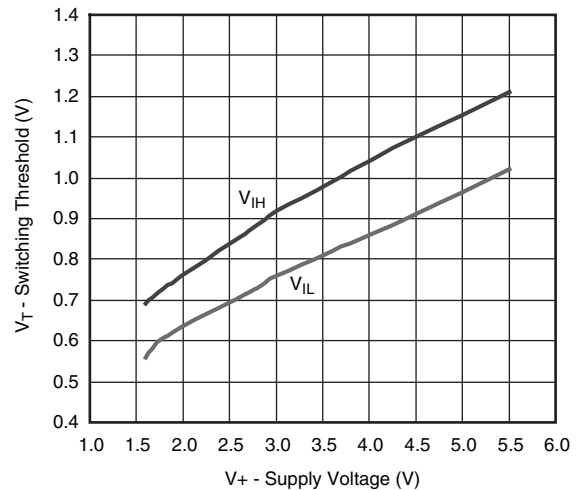
Charge Injection vs. Analog Voltage



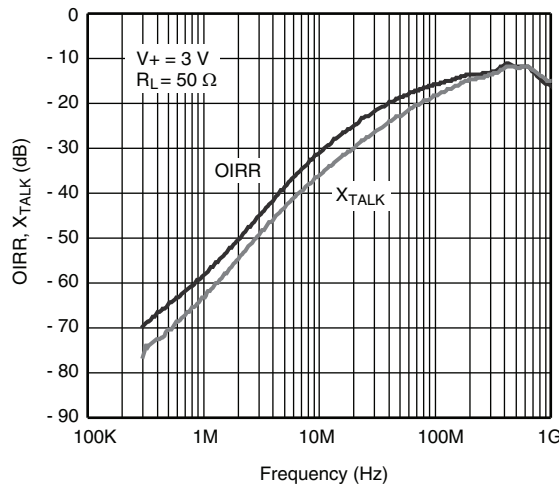
Insertion Loss vs. Frequency



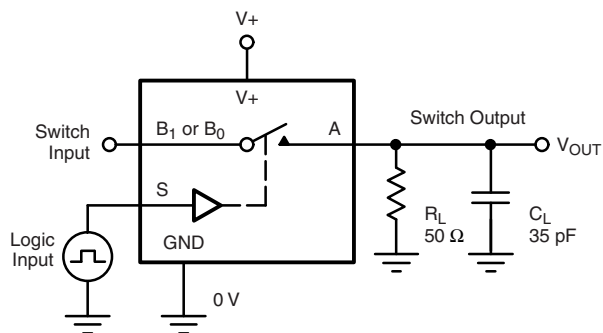
Switching Time vs. Temperature



Switching Threshold vs. Supply Voltage



Off-Isolation and Crosstalk vs. Frequency

TEST CIRCUITS

 C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_A \left(\frac{R_L}{R_L + R_{ON}} \right)$$

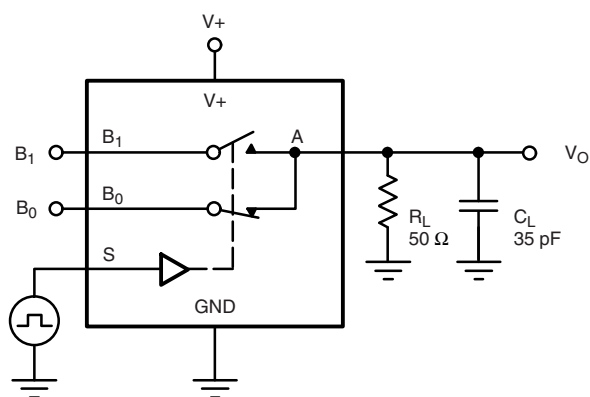
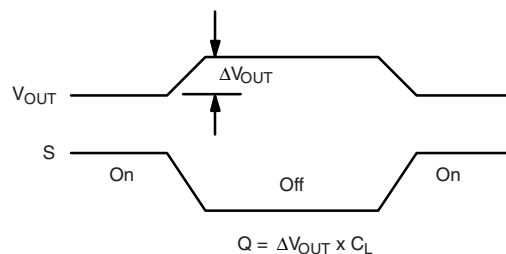
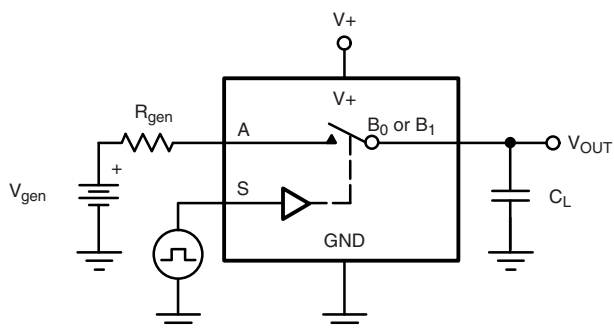
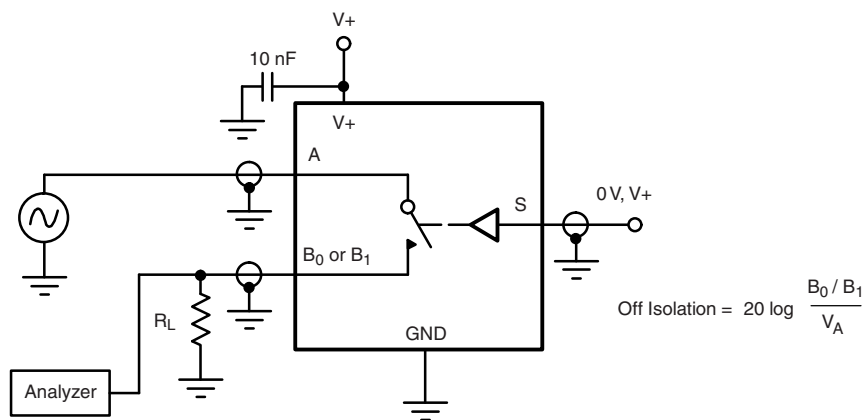
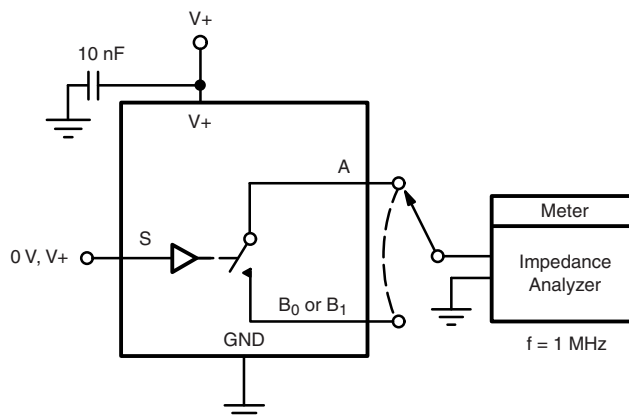
Fig. 1 - Switching Time

 C_L (includes fixture and stray capacitance)

Fig. 2 - Break-Before-Make Interval


$Q = \Delta V_{OUT} \times C_L$

S depends on switch configuration: input polarity determined by sense of switch.

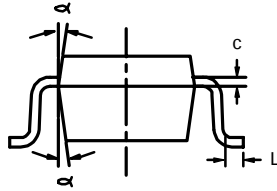
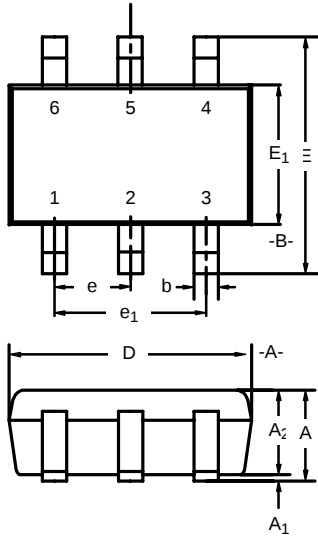
Fig. 3 - Charge Injection

TEST CIRCUITS

Fig. 4 - Off-Isolation

Fig. 5 - Channel Off/On Capacitance

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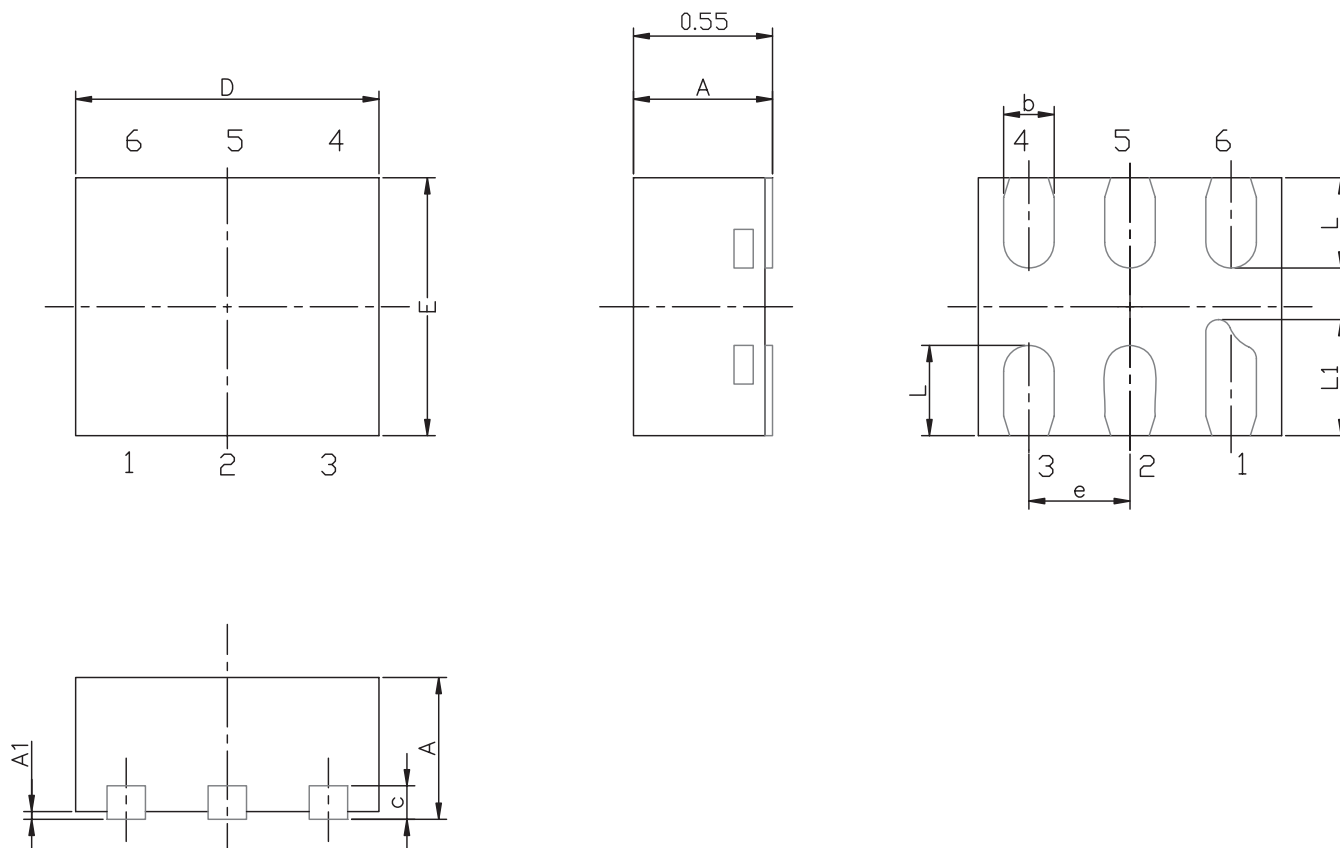
SC-70: 6-LEADS



Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.90	—	1.10	0.035	—	0.043
A ₁	—	—	0.10	—	—	0.004
A ₂	0.80	—	1.00	0.031	—	0.039
b	0.15	—	0.30	0.006	—	0.012
c	0.10	—	0.25	0.004	—	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
E	1.80	2.10	2.40	0.071	0.083	0.094
E ₁	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65BSC			0.026BSC		
e ₁	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
α	7°Nom			7°Nom		

ECN: S-03946—Rev. B, 09-Jul-01
DWG: 5550

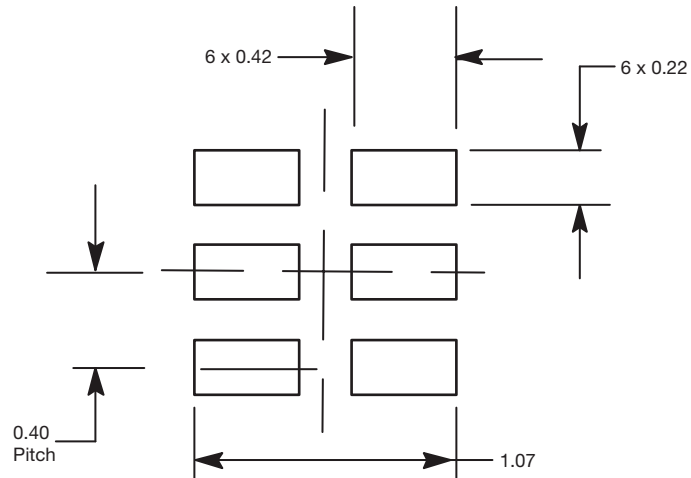
MINI QFN-6L CASE OUTLINE



DIM	MILLIMETERS			INCHES		
	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.
A	0.50	0.55	0.60	0.0197	0.0217	0.0236
A1	0.00	-	0.05	0.000	-	0.002
b	0.15	0.20	0.25	0.006	0.008	0.010
c	0.15 REF			0.006 REF		
D	1.15	1.20	1.25	0.045	0.047	0.049
E	0.95	1.00	1.05	0.037	0.039	0.041
e	0.40 BSC			0.016 BSC		
L	0.30	0.35	0.40	0.012	0.014	0.016
L1	0.40	0.45	0.50	0.016	0.018	0.020

ECN T-07039-Rev. A, 12-Feb-07
DWG: 5958

RECOMMENDED MINIMUM PADS FOR MINI QFN 6L



Mounting Footprint
Dimensions in mm



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